

DESCRIPTION

The fundamental of SP6016D synchronous rectifier (SR) driver IC is based on our U.S. patented methods that utilize the principle of "prediction" logic circuit. The IC deliberates previous cycle timing to control the SR in present cycle by "predictive" algorithm that makes adjustments to the turn-off time, in order to achieve maximum efficiency and avoid cross-conduction at the same time. Specially, SP6016D is designed for Resonance. It also maintains the MOSFET's body diode conduction at minimum level. The SP6016D is capable to almost all existing Resonance converters with few adjustments considered necessary.

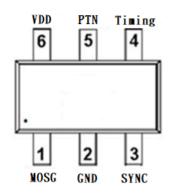
FEATURES

- Offers efficiency improvement over Schottky Diode
- Low Standby Power to meet DOE Lot 6 requirement.
- Drives all logic level Power MOSFET.
- Prediction gate timing control.
- Minimum MOSFET body diode conduction.
- Operating frequency up to 400 KHz.
- Synchronize to transformer secondary voltage waveform.
- Minimum on time 0.45us ~ 0.85us
- Internal 15K Ω resistor to GND at MOSG pin
- External timing pin to adjust the falling slope
- Internal over voltage protection

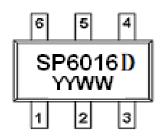
APPLICATIONS

- Switching Mode Power Supply
- Storage area network power supplies
- Telecommunication converters
- Embedded systems
- Industrial & commercial systems using high current processors
- Power converters to meet Lot 6 requirement

PIN CONFIGURATION (SOT-23-6L)



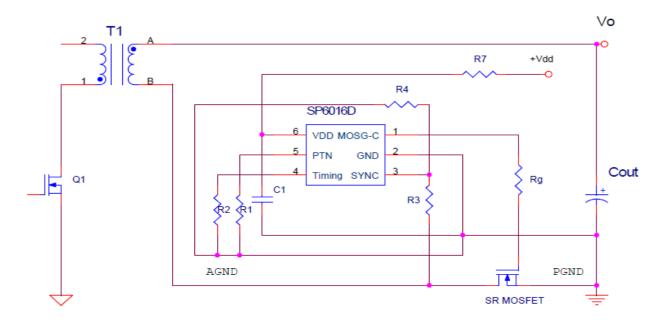
PART MARKING



Y: Year Code W: Week Code



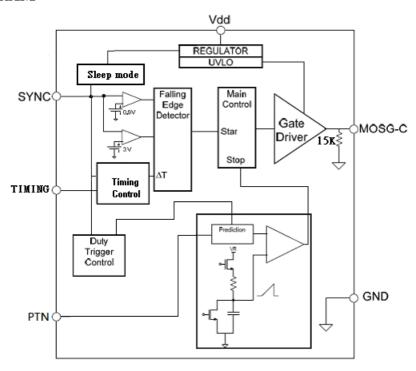
TYPICAL APPLCATION CIRCUIT



PIN DESCRIPTION

Pin	Symbol	Description
1	MOSG-C	Catch MOSFET gate drive.
2	GND	Ground connection.
3	SYNC	Synchronized signal from the VDS of SR MOSFET.
4	Timing	Discontinuous current filter timing adjustment resistor connection.
5	PTN	Connecting a resistor to ground to set the dead time and dynamic trigger point
6	Vdd	DC supply voltage.

BLOCK DIAGRAM



ORDERING INFORMATION

Part Number	Package	Part Marking		
SP6016DS26RGB	SOT-23-6L	SP6016D		

[※] SP6016DS26RGB: Tape Reel; Pb − Free; Halogen - Free

ABSOULTE MAXIMUM RATINGS (TA=25°C, unless otherwise specified.)

The following ratings designate persistent limits beyond which damage to the device may occur.

Symbol	Parameter Valu		Unit
V_{dd}	DC Supply Voltage	17	V
I_{OUT}	Peak Source Current (Pulsed)	1.0	A
	Peak Sink Current (Pulsed)	1.5	A
P_D	Power Dissipation @ $T_A=85^{\circ}C$ (*)	0.3	W
T_{J}	Operating Junction Temperature Range	-40 to125	$^{\circ}\!\mathbb{C}$
T _{STG}	Storage Temperature Range	-40 to 150	$^{\circ}\!\mathbb{C}$
T_{LEAD}	Lead Soldering Temperature for 5 sec.	260	$^{\circ}\!\mathbb{C}$

THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
Rөjc	Thermal Resistance Junction – Case (*)	110	°C/W

^(*) The power dissipation and thermal resistance are evaluated under copper board mounted with free air conditions.

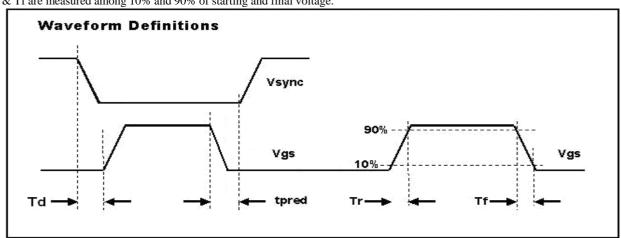


ELECTRICAL CHARACTERISTICS

 $(T_A=25^{\circ}\text{C}, V_{dd}=12\text{V}, \text{Freq.}=50 \text{ KHz}, \text{Duty Cycle}=50\%, \text{unless otherwise specified.})$

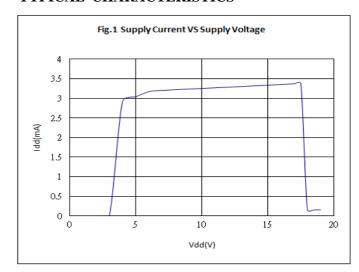
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
SUPPLY INI	PUT			* *		
Idd	C1	Sleep mode		0.15		mA
	Supply current	V _{SYNC} =Vdd, Normal mode		3		mA
Vdd	Supply voltage	Idd peak < 1A	4.5		16	V
Vdd on	Enable voltage			3.7	4.2	V
Vdd	Enable voltage			0.3	0.5	V
hysteresis						v
Vovp	Over voltage protection		17	17.5	18.5	V
Vovp			0.5	0.7	1	V
hysteresis						v
SYNC REFE	ERENCE (SYNC)					
Vshth	SYNC high threshold			3.0		V
Vslth	SYNC low threshold			0.9		V
Vsync	SYNC clamp voltage	Isync=3mA	Vdd+2.0			V
Vsync WK		Pulse width >1uS for Vdd=5V	7			V
Vsync WK	SYNC wake-up voltage	Pulse width >1uS for Vdd=12V	8.0			V
Isync	SYNC input current				3	mA
REFERENC	CE Voltage (V_PTN)					
V_PTN				1.25		V
ON TIME D	UTY SETUP (PIN 1)					
Ton-time		Frequency= 10KHz-20KHz, Duty=20%~50%		25		uS
MOSFET GA	ATE DRIVER (MOSG-C)					
Voh	Output high voltage	Io = -200mA		10.8		V
Vol	Output low voltage	Io = 200mA		0.2		V
Td	Propagation delay	No load,R_PTN=9.1KΩ		100		nS
Tpred	Dead time	No load,R_PTN=9.1KΩ		230		nS
Tr	Rise time	Load = 1nF (*)		13		nS
Tf	Fall time	Load = 1nF (*)		7		nS
Dynamic Pro	otect	. ,			•	•
Dt	Dynamic variable	Pin 5=9.1KΩ		1100		nS
Ton-min	MOSG-C on time	PWM adjusts time > Dt	0.45		0.85	uS

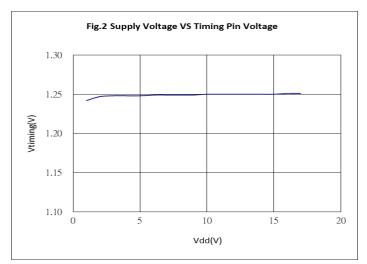
(*) Tr & Tf are measured among 10% and 90% of starting and final voltage.

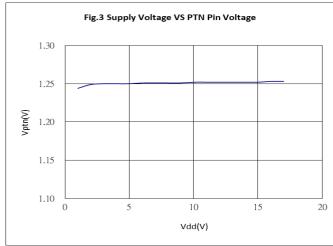


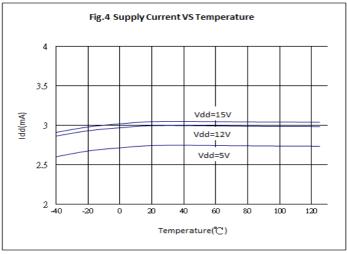


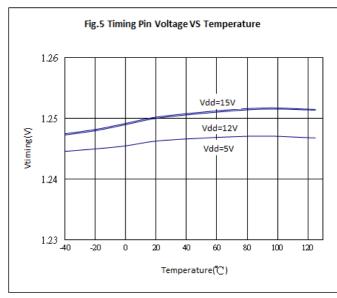
TYPICAL CHARACTERISTICS

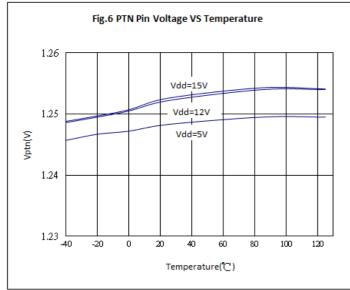




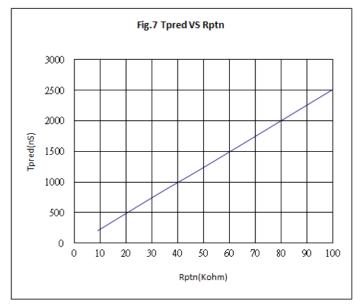


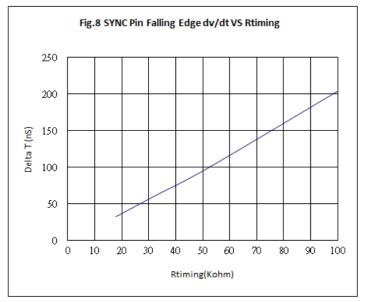


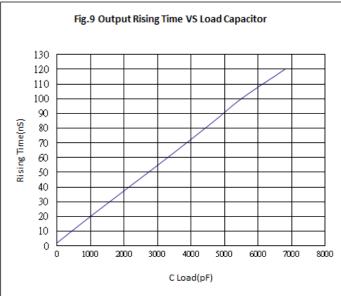


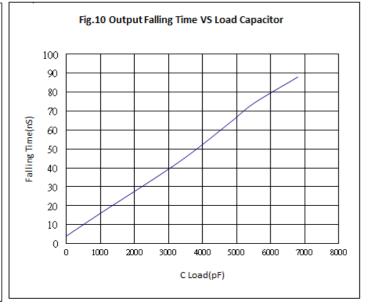


TYPICAL CHARACTERISTICS









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